

FLAT BAND OF MIDGAP ROTATING SURFACE STATES IN 3D DIRAC AND WEYL SEMIMETALS UNDER RADIATION



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3D SEMIMETALS

We start with a model of 3D Dirac semimetal

$$H_0 = M(\mathbf{k}) \,\sigma_z + \hbar v \left(\zeta \, k_x \sigma_x + k_y \sigma_y\right) \qquad \zeta = \pm M(\mathbf{k}) = m_0 - m_1 k_z^2 - m_2 (k_x^2 + k_y^2)$$

The low-energy spectrum has two Dirac points at $\mathbf{k}_{c} = (0, 0, \pm \sqrt{m_{0} / m_{1}})$



Near the Dirac points, the dispersion becomes linear in all directions in momentum space

$$\varepsilon_0(\mathbf{k}) = \pm \sqrt{\hbar^2 v^2 (k_x^2 + k_y^2) + 4m_0 m_1 (k_z - k_c)^2}$$

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2D AND 3D SEMIMETALS UNDER CIRCULARLY POLARIZED RADIATION



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3D DIRAC SEMIMETALS UNDER RADIATION

We investigate the changes in the spectrum when illuminating with circularly polarized light, corresponding to a vector potential

$$\mathbf{A}(t) = A(\eta \sin(\Omega t), \cos(\Omega t), 0) \qquad \eta = \pm 1$$

We use Floquet theory to find the solutions of the time-dependent Schrödinger equation

$$-i\hbar\partial_{t} |\Psi(t)\rangle = H(t) |\Psi(t)\rangle$$
$$|\Psi(t)\rangle = e^{-i\varepsilon t/\hbar} |\Phi(t)\rangle , |\Phi(t+T)\rangle = |\Phi(t)\rangle \quad T = 2\pi/\Omega$$

which amounts to find the result of hybridizing a number of Floquet subbands

$$\begin{split} \left| \Phi(t) \right\rangle &= \sum_{m} e^{-im\Omega t} \left| \chi_{m}^{(\alpha)} \right\rangle ,\\ \sum_{n} H_{mn} \left| \chi_{n}^{(\alpha)} \right\rangle &= \left(\varepsilon_{\alpha} + m\hbar\Omega \right) \left| \chi_{m}^{(\alpha)} \right\rangle \\ H_{mn} &= \left(1/T \right) \int_{0}^{T} dt \ H(t) \ e^{i(m-n)\Omega} \end{split}$$



3D DIRAC SEMIMETALS UNDER RADIATION

$$\sum_{n} H_{mn} \left| \chi_{n}^{(\alpha)} \right\rangle = \left(\varepsilon_{\alpha} + m\hbar\Omega \right) \left| \chi_{m}^{(\alpha)} \right\rangle$$

In our model we have

$$H_{nn} = H_0 + n\hbar\Omega \mathbf{1} - m_2 A^2 \sigma_z$$

$$H_{n+1,n} = (\hbar v/2) A(i\sigma_x - \sigma_y) + m_2 A(-ik_x - k_y) \sigma_z$$

$$H_{n-1,n} = (\hbar v/2) A(-i\sigma_x - \sigma_y) + m_2 A(ik_x - k_y) \sigma_z$$

The hybridization of the Floquet subbands gives rise to a gap over an extended ring in momentum space:

- **proportional to** *A* between subbands n = 0 and $n = \pm 1$
- **proportional to** A^2 between subbands n = -1 and n = 1



3D DIRAC SEMIMETALS UNDER RADIATION

But most interestingly, we can have evanescent states localized at the irradiated surface.

These states come as solutions with real quasi-energy ε_{α} for complex momenta k_z

$$\chi^{(\alpha)} \sim e^{ik_z z}$$
 , $k_z = k_R + ik_Z$

Computing for a wire with finite section in the *x*-*y* plane $(150 \times 150 \text{ Å}^2)$



we find evanescent states (for $\text{Im}(k_z) \approx 0.01 \text{ Å}^{-1}$) at the position of the dots within the gap between Floquet subbands in the figure.

J. G. and R. A. Molina, arXiv:1512.03753 (PRL, to appear)

WEYL SEMIMETALS UNDER RADIATION

We can have a deeper insight by solving for a single Weyl quasiparticle

 $H_{W} = -i\hbar \left(v\sigma_{x}\partial_{x} + v\sigma_{y}\partial_{y} + v_{z}\sigma_{z}\partial_{z} \right)$ $+ \hbar v A \left(\sigma_{x} \cos(\Omega t) + \sigma_{y} \sin(\Omega t) \right)$

 H_W can be translated to time-independent form by making a unitary transformation

$$\widetilde{H}_{W} = U^{+}H_{W}U - i\hbar U^{+}\partial_{t}U \qquad U = e^{-iJ_{z}\Omega t/\hbar}$$
$$= -i\hbar \left(v\sigma_{x}\partial_{x} + v\sigma_{y}\partial_{y} + v_{z}\sigma_{z}\partial_{z}\right) - \Omega J_{z} + \hbar vA\sigma_{x}$$

and transforming again we obtain

$$\begin{split} \widetilde{H}'_{W} &= P^{+} \widetilde{H}_{W} P \qquad \qquad P = e^{-iAx} \\ &= -i\hbar v \sum e^{\mp i\theta} \left(\partial_{r} \mp (i/r) \partial_{\theta} \right) \sigma_{\pm} - i\hbar v_{z} \sigma_{z} \partial_{z} \\ &- \Omega J_{z} - \hbar \Omega Ar \sin(\theta) \qquad \qquad J_{z} = -i\hbar \partial_{\theta} + \hbar \sigma_{z} \Lambda \\ \end{split}$$

2

We find that the spectrum has a gap between Floquet subbands with $j_z = \hbar/2$ and $j_z = -\hbar/2$



WEYL SEMIMETALS UNDER RADIATION

The gap has oscillations as a function of k_z which are the signature of branch points in the complex plane $\varepsilon(k_z) \sim \sqrt{k_i - k_z} \sqrt{\overline{k_i} - k_z}$



 k_i , $\overline{k_i}$ are exceptional points at which $\varepsilon(k_z) = 0$, leading to a segment of real values of ε for $|\text{Im}(k_z)| \le |\text{Im}(k_i)|$

The set of exceptional points corresponds to a sequence of evanescent states localized at the irradiated surface, with a peculiar quantization pattern



WEYL SEMIMETALS UNDER RADIATION

The most important feature of the evanescent states is that they carry an angular current j^{θ} corresponding to the flow of probability density

$$\partial_t (\psi^+ \psi) \approx \partial_\theta j^\theta$$

 j^{θ} can be computed in the space spanned by the states with $j_z = \pm \hbar/2$

$$\chi = \begin{pmatrix} \phi_1(r) \\ e^{i\theta}\phi_2(r) \end{pmatrix} e^{ik_z z} + \begin{pmatrix} e^{-i\theta}\phi_3(r) \\ \phi_4(r) \end{pmatrix} e^{ik_z z}$$

The angular current has a uniform component, which is in general negligible,

$$j_{\text{static}}^{\theta} = -i \frac{v}{r} \Big(\phi_1^*(r) \, \phi_2(r) \, + \, \phi_3^*(r) \, \phi_4(r) \, \Big) \, + \, \text{h.c.}$$

and a time-dependent component

$$j_{\Omega}^{\theta} = -i \frac{v}{r} \left(\phi_1^*(r) \, \phi_4(r) \, e^{-i(\theta - \Omega t)} + \, \phi_3^*(r) \, \phi_2(r) \, e^{i(\theta - \Omega t)} \right) + \, \text{h.c.}$$



The corresponding current intensities have magnitudes $\int dr r j_{\Omega}^{\theta} \sim 10^{-3} v/a - 10^{-2} v/a$ J. G. and R. A. Molina, arXiv:1512.03753 (PRL, to appear)

3D SEMIMETALS UNDER CIRCULARLY POLARIZED RADIATION

In conclusion,

The irradiation of the surface of 3D semimetals must lead to the observation of evanescent states carrying a non negligible angular current. The feasibility of this observation may be supported by several facts:

- the limited screening in the 3D semimetals, which has to allow the infrared radiation to penetrate sufficiently deep (~1 μm at Ω~100 THz)
- the magnitude of the angular current of individual states, which have associated a current intensity

 $e\int dr \ r \ j_{\Omega}^{\theta} \sim 10^{-1} \,\mu\text{A} - 1 \,\mu\text{A}$

the possibility of devising an experimental setup to work as a rectenna, benefiting from recent advances to rectify currents oscillating at the frequency of visible light

